NSN 5961-01-168-8061

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-168-8061 **Inclosure Material:** Plastic or ceramic **Overall Length:** 0.785 inches **Overall Height:** 0.200 inches **Overall Width:** 0.310 inches **Component Name And Quantity:** 16 semiconductor device diode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 55.0 reverse voltage, peak all semiconductor device diode **Current Rating Per Characteristic:** 350.00 milliamperes source cutoff current preset all semiconductor device diode **Special Features:** Inertial measuring unit; Shelf Life: N/a **Unit Of Measure: Demilitarization:** No